

# 74AHC2G08; 74AHCT2G08

Dual 2-input AND gate

Rev. 02 — 18 October 2004

Product data sheet

## 1. General description

The 74AHC2G08; 74AHCT2G08 is a high-speed Si-gate CMOS device.

The 74AHC2G08; 74AHCT2G08 provides two 2-input AND gates.

## 2. Features

- Symmetrical output impedance
- High noise immunity
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
  - ◆ MM EIA/JESD22-A115-A exceeds 200 V
  - ◆ CDM EIA/JESD22-C101 exceeds 1000 V.
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+80\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$ .

## 3. Quick reference data

**Table 1: Quick reference data**

$GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $t_r = t_f \leq 3.0\text{ ns}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Type 74AHC2G08</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay A and B to Y	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	-	3.2	5.9	ns
$C_I$	input capacitance		-	1.5	10	pF
$C_{PD}$	power dissipation capacitance	$C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$	<a href="#">[1]</a> <a href="#">[2]</a>	-	17	pF

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**Table 1: Quick reference data ...continued** $GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ °C}$ ;  $t_r = t_f \leq 3.0\text{ ns}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Type 74AHCT2G08</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay A and B to Y	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	-	3.6	6.2	ns
$C_I$	input capacitance		-	1.5	10	pF
$C_{PD}$	power dissipation capacitance	$C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$	[1][2]	19	-	pF

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in Volts;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[2] The condition is  $V_i = GND$  to  $V_{CC}$ .

## 4. Ordering information

**Table 2: Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74AHC2G08DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74AHCT2G08DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74AHC2G08DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AHCT2G08DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AHC2G08GM	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $0.95 \times 1.95 \times 0.5\text{ mm}$	SOT833-1
74AHCT2G08GM	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $0.95 \times 1.95 \times 0.5\text{ mm}$	SOT833-1

## 5. Marking

**Table 3: Marking**

Type number	Marking code
74AHC2G08DP	A08
74AHCT2G08DP	C08
74AHC2G08DC	A08
74AHCT2G08DC	C08
74AHC2G08GM	A08
74AHCT2G08GM	C08

## 6. Functional diagram

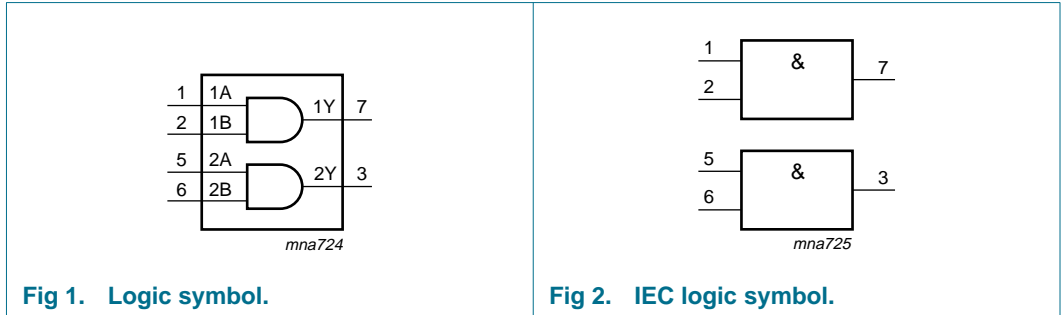


Fig 1. Logic symbol.

Fig 2. IEC logic symbol.

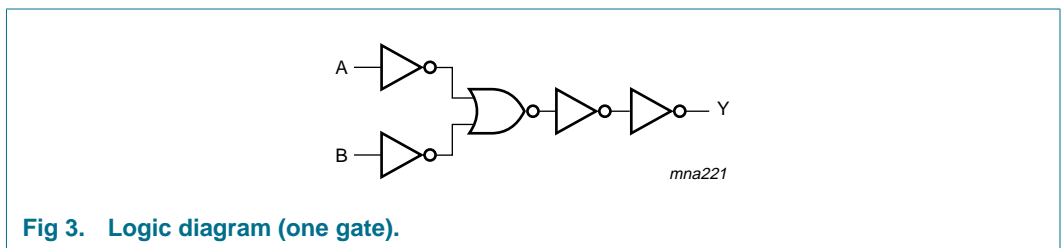


Fig 3. Logic diagram (one gate).

## 7. Pinning information

### 7.1 Pinning

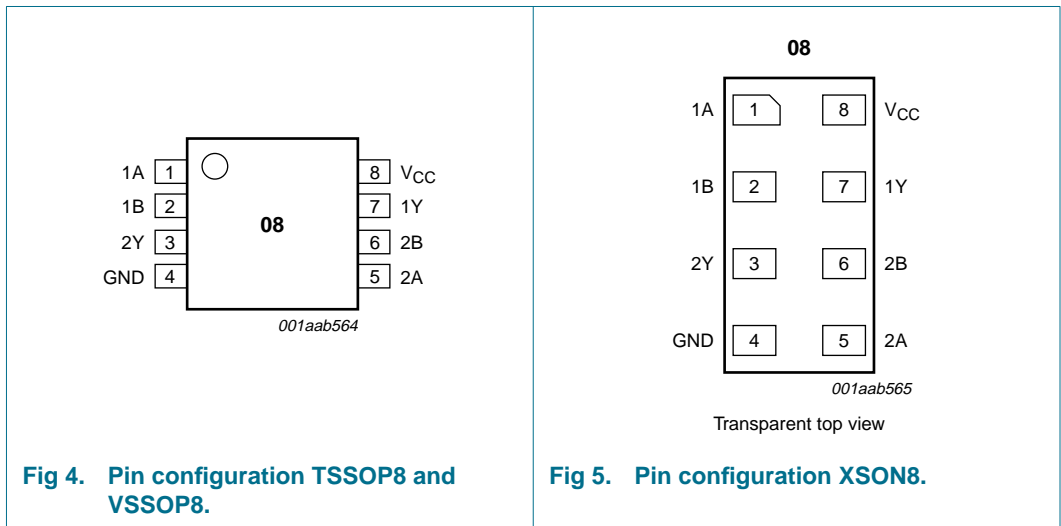


Fig 4. Pin configuration TSSOP8 and VSSOP8.

Fig 5. Pin configuration XSON8.

## 7.2 Pin description

Table 4: Pin description

Symbol	Pin	Description
1A	1	data input
1B	2	data input
2Y	3	data output
GND	4	ground (0 V)
2A	5	data input
2B	6	data input
1Y	7	data output
V <sub>CC</sub>	8	supply voltage

## 8. Functional description

### 8.1 Function table

Table 5: Function table <sup>[1]</sup>

Input		Output
nA	nB	nY
L	L	L
L	H	L
H	L	L
H	H	H

[1] H = HIGH voltage level;  
L = LOW voltage level.

## 9. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
V <sub>I</sub>	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input diode current	V <sub>I</sub> < -0.5 V	-	-20	mA
I <sub>OK</sub>	output diode current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	<sup>[1]</sup> -	±20	mA
I <sub>O</sub>	output source or sink current	V <sub>O</sub> > -0.5 V and V <sub>O</sub> < V <sub>CC</sub> + 0.5 V	-	±25	mA
I <sub>CC</sub> , I <sub>GND</sub>	V <sub>CC</sub> or GND current		-	±75	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 10. Recommended operating conditions

Table 7: Recommended operating operations

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Type 74AHC2G08</b>						
$V_{CC}$	supply voltage		2.0	5.0	5.5	V
$V_I$	input voltage		0	-	5.5	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$T_{amb}$	ambient temperature	see <a href="#">Section 11</a> and <a href="#">Section 12</a>	-40	+25	+125	°C
$t_r, t_f$	input rise and fall times	$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	-	-	100	ns/V
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	20	ns/V
<b>Type 74AHCT2G08</b>						
$V_{CC}$	supply voltage		4.5	5.0	5.5	V
$V_I$	input voltage		0	-	5.5	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$T_{amb}$	ambient temperature	see <a href="#">Section 11</a> and <a href="#">Section 12</a>	-40	+25	+125	°C
$t_r, t_f$	input rise and fall times	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	20	ns/V

## 11. Static characteristics

Table 8: Static characteristics type 74AHC2G08

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25\text{ °C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 2.0\text{ V}$	1.5	-	-	V
		$V_{CC} = 3.0\text{ V}$	2.1	-	-	V
		$V_{CC} = 5.5\text{ V}$	3.85	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 2.0\text{ V}$	-	-	0.5	V
		$V_{CC} = 3.0\text{ V}$	-	-	0.9	V
		$V_{CC} = 5.5\text{ V}$	-	-	1.65	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}\text{ or }V_{IL}$				
		$I_O = -50\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$	1.9	2.0	-	V
		$I_O = -50\text{ }\mu\text{A}; V_{CC} = 3.0\text{ V}$	2.9	3.0	-	V
		$I_O = -50\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$	4.4	4.5	-	V
		$I_O = -4.0\text{ mA}; V_{CC} = 3.0\text{ V}$	2.58	-	-	V
	$I_O = -8.0\text{ mA}; V_{CC} = 4.5\text{ V}$	3.94	-	-	V	

**Table 8: Static characteristics type 74AHC2G08 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V	-	0	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.36	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	0.1	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	1.0	μA
C <sub>I</sub>	input capacitance		-	1.5	10	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 3.0 V	2.1	-	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 3.0 V	-	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V	2.9	-	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.48	-	-	V
		I <sub>O</sub> = -8.0 mA; V <sub>CC</sub> = 4.5 V	3.8	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V	-	-	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
		I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.44	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	1.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	10	μA
C <sub>I</sub>	input capacitance		-	-	10	pF
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 3.0 V	2.1	-	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 3.0 V	-	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	V

**Table 8:** Static characteristics type 74AHC2G08 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -50 µA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -50 µA; V <sub>CC</sub> = 3.0 V	2.9	-	-	V
		I <sub>O</sub> = -50 µA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -8.0 mA; V <sub>CC</sub> = 4.5 V	3.70	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 3.0 V	-	-	0.1	V
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.55	V
		I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.55	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	2.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	40	µA
C <sub>I</sub>	input capacitance		-	-	10	pF

**Table 9:** Static characteristics type 74AHCT2G08

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -50 µA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -8.0 mA; V <sub>CC</sub> = 4.5 V	3.94	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.36	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V	-	-	0.1	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	1.0	µA
ΔI <sub>CC</sub>	additional quiescent supply current per input pin	V <sub>I</sub> = 3.4 V; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	1.35	mA
C <sub>I</sub>	input capacitance		-	1.5	10	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V

**Table 9: Static characteristics type 74AHCT2G08 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -50 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	4.4	-	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 50 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	-	-	0.1	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.44	V
$I_{LI}$	input leakage current	$V_I = V_{IH}$ or $V_{IL}; V_{CC} = 5.5 \text{ V}$	-	-	1.0	$\mu\text{A}$
$I_{CC}$	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}; V_{CC} = 5.5 \text{ V}$	-	-	10	$\mu\text{A}$
$\Delta I_{CC}$	additional quiescent supply current per input pin	$V_I = 3.4 \text{ V};$ other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}; V_{CC} = 5.5 \text{ V}$	-	-	1.5	mA
$C_I$	input capacitance		-	-	10	pF
<b><math>T_{amb} = -40 \text{ }^\circ\text{C}</math> to <math>+125 \text{ }^\circ\text{C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V}$ to $5.5 \text{ V}$	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5 \text{ V}$ to $5.5 \text{ V}$	-	-	0.8	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -50 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	4.4	-	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.70	-	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 50 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	-	-	0.1	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	V
$I_{LI}$	input leakage current	$V_I = V_{IH}$ or $V_{IL}; V_{CC} = 5.5 \text{ V}$	-	-	2.0	$\mu\text{A}$
$I_{CC}$	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}; V_{CC} = 5.5 \text{ V}$	-	-	40	$\mu\text{A}$
$\Delta I_{CC}$	additional quiescent supply current per input pin	$V_I = 3.4 \text{ V};$ other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}; V_{CC} = 5.5 \text{ V}$	-	-	1.5	mA
$C_I$	input capacitance		-	-	10	pF

## 12. Dynamic characteristics

**Table 10: Dynamic characteristics type 74AHC2G08**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $t_r = t_f \leq 3.0$  ns; see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nA and nB to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 3.0$ V to $3.6$ V; $C_L = 15$ pF	[1] -	4.6	8.8	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 15$ pF	[2] -	3.2	5.9	ns
		$V_{CC} = 3.0$ V to $3.6$ V; $C_L = 50$ pF	[1] -	6.5	12.3	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 50$ pF	[2] -	4.6	7.9	ns
$C_{PD}$	power dissipation capacitance	$C_L = 50$ pF; $f_i = 1$ MHz	[3] [4] -	17	-	pF
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nA and nB to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 3.0$ V to $3.6$ V; $C_L = 15$ pF	1.0	-	10.5	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 15$ pF	1.0	-	7.0	ns
		$V_{CC} = 3.0$ V to $3.6$ V; $C_L = 50$ pF	1.0	-	14.0	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 50$ pF	1.0	-	9.0	ns
<b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nA and nB to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 3.0$ V to $3.6$ V; $C_L = 15$ pF	1.0	-	12.0	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 15$ pF	1.0	-	8.0	ns
		$V_{CC} = 3.0$ V to $3.6$ V; $C_L = 50$ pF	1.0	-	16.0	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 50$ pF	1.0	-	10.5	ns

[1] Typical values are measured at  $V_{CC} = 3.3$  V.

[2] Typical values are measured at  $V_{CC} = 5.0$  V.

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in Volts;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[4] The condition is  $V_I = \text{GND}$  to  $V_{CC}$ .

**Table 11: Dynamic characteristics type 74AHCT2G08**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $t_r = t_f \leq 3.0$  ns; see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nA and nB to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 15$ pF	[1] -	3.6	6.2	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 50$ pF	[1] -	5.1	7.9	ns
$C_{PD}$	power dissipation capacitance	$C_L = 50$ pF; $f_i = 1$ MHz	[2][3] -	19	-	pF
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nA and nB to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 15$ pF	1.0	-	7.1	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 50$ pF	1.0	-	9.0	ns
<b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nA and nB to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 15$ pF	1.0	-	8.0	ns
		$V_{CC} = 4.5$ V to $5.5$ V; $C_L = 50$ pF	1.0	-	10.5	ns

[1] Typical values are measured at  $V_{CC} = 5.0$  V.

[2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

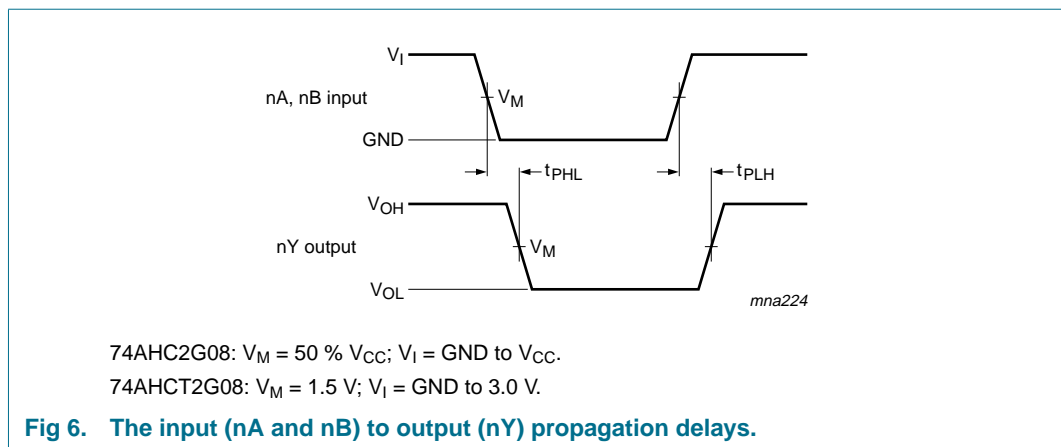
$V_{CC}$  = supply voltage in Volts;

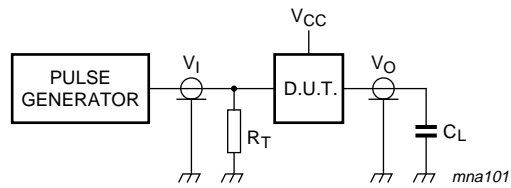
$N$  = total load switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[3] The condition is  $V_I = \text{GND}$  to  $V_{CC}$ .

## 13. Waveforms





Definitions for test circuit:

$C_L$  = Load capacitance including jig and probe capacitance (See [Section 12](#) for the value).

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

**Fig 7. Load circuitry for switching times.**

14. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

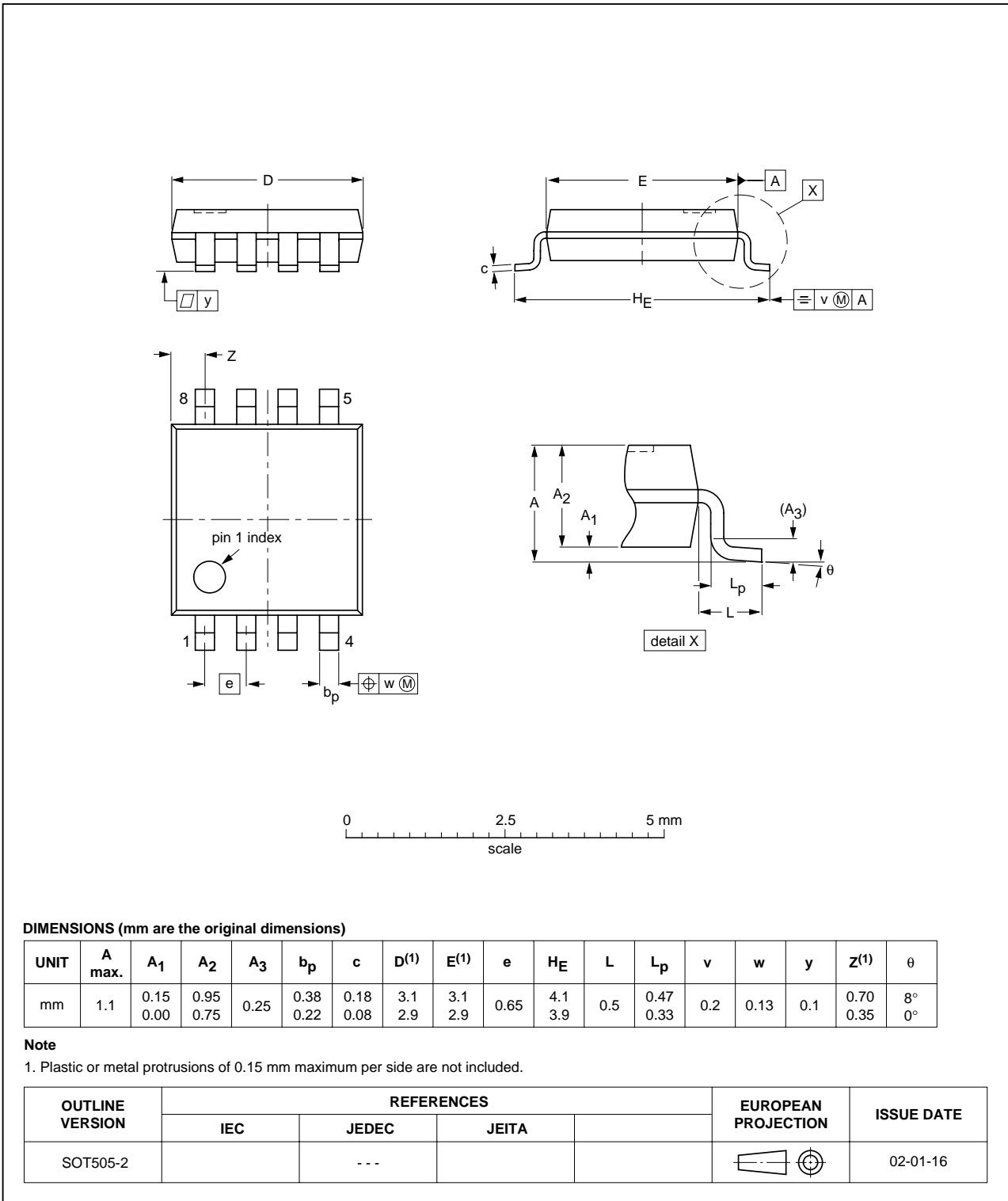


Fig 8. Package outline SOT505-2 (TSSOP8).

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

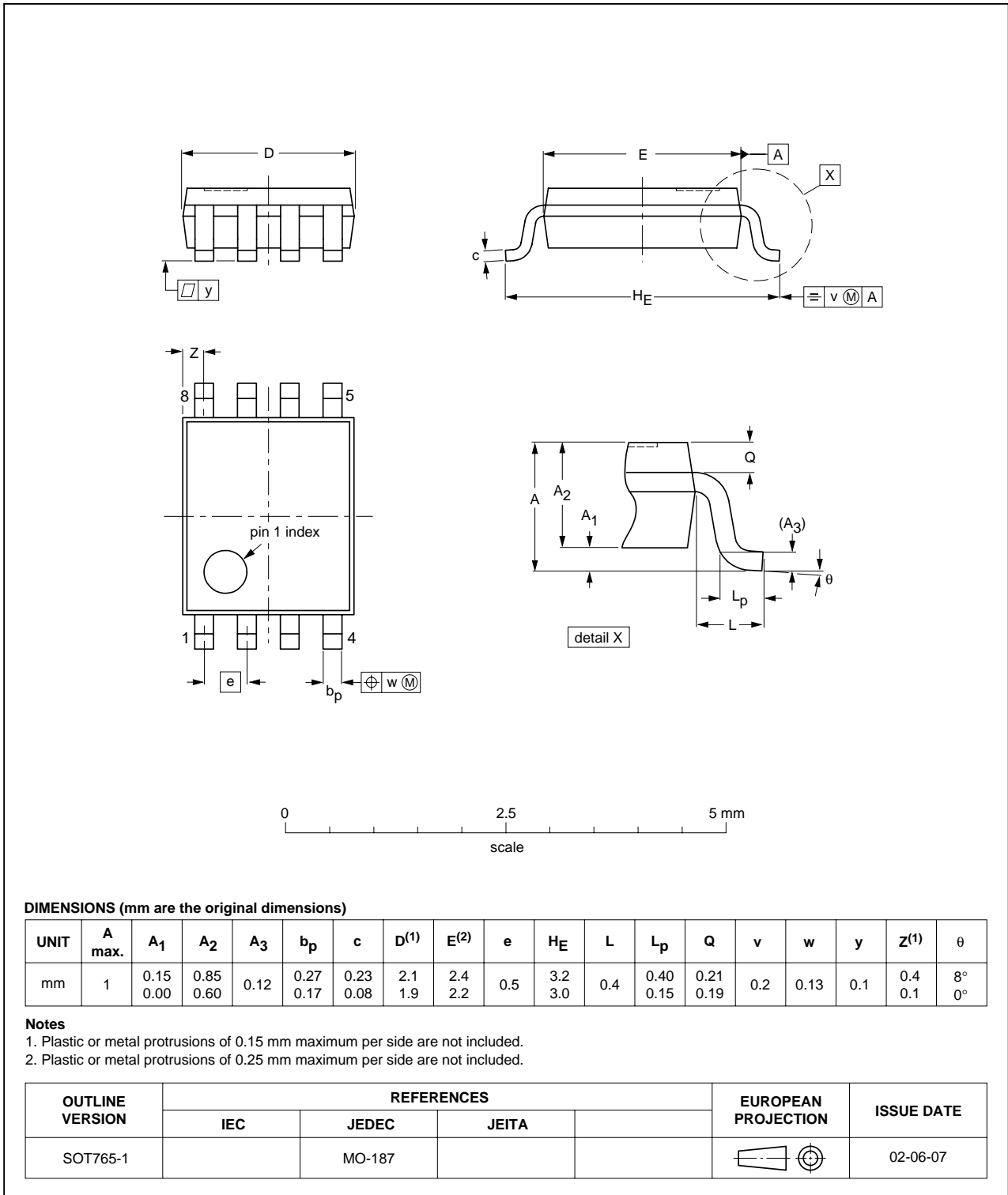
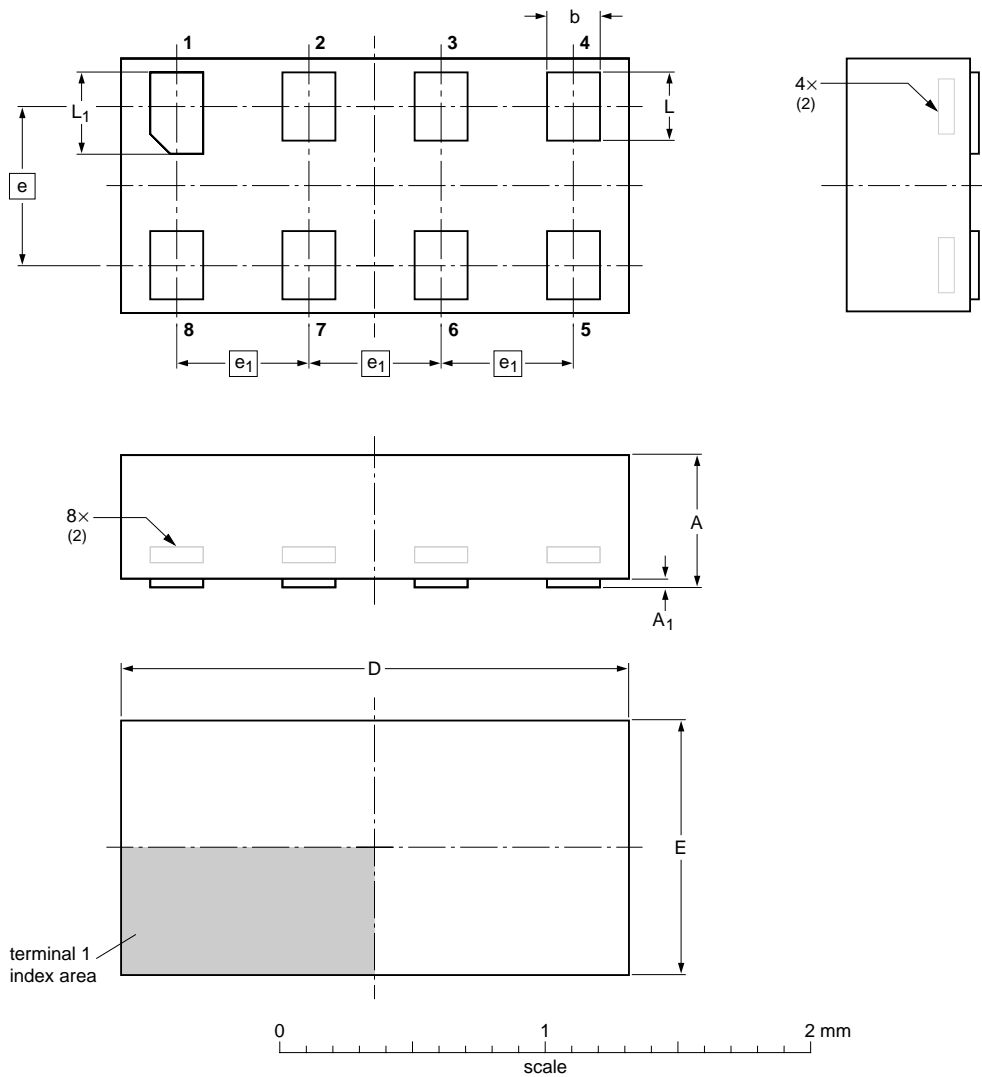


Fig 9. Package outline SOT765-1 (VSSOP8).

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 0.95 x 1.95 x 0.5 mm

SOT833-1



**DIMENSIONS (mm are the original dimensions)**

UNIT	A <sup>(1)</sup> max	A <sub>1</sub> max	b	D	E	e	e <sub>1</sub>	L	L <sub>1</sub>
mm	0.5	0.04	0.25 0.17	2.0 1.9	1.0 0.9	0.6	0.5	0.35 0.27	0.40 0.32

**Notes**

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT833-1	---	MO-252	---			04-07-15 04-07-22

Fig 10. Package outline SOT833\_1 (XSON8).

## 15. Revision history

Table 12: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
74AHC_AHCT2G08_2	20041018	Product data sheet	-	9397 750 13735	74AHC_AHCT2G08_1
Modifications:	Adding features, ordering information, pinning, and package outline				
74AHC_AHCT2G08_1	20040206	Product data sheet	-	9397 750 12533	-

## 16. Data sheet status

Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2]</sup> <sup>[3]</sup>	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

## 17. Definitions

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**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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For sales office addresses, send an email to: [sales.addresses@www.semiconductors.philips.com](mailto:sales.addresses@www.semiconductors.philips.com)

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